

FEATURES

Ultralow on resistance

0.28 Ω typical

0.48 Ω max at 125°C

Excellent audio performance, ultralow distortion

0.025 Ω typical

0.052 Ω max R_{ON} flatness

1.65 V to 3.6 V single supply

High current carrying capability

300 mA continuous current

500 mA peak current

Automotive temperature range: -40°C to +125°C

Rail-to-rail operation

Typical power consumption (<0.01 μ W)

APPLICATIONS

Handsets

PDA's

MP3 players

Power routing

Battery-powered systems

Communication systems

Modems

PCMCIA cards

GENERAL DESCRIPTION

The ADG841 and ADG842 are low voltage CMOS devices containing a single-pole, single-throw (SPST) switch. The ADG841 is closed for a Logic 1 input and the ADG842 is open for a Logic 1 input. The devices offer ultralow on resistance of less than 0.48 Ω over the full temperature range. The ADG841/ADG842 are fully specified for 3.3 V, 2.5 V, and 1.8 V supply operation.

Each switch conducts equally well in both directions when on, and has an input signal range that extends to the supplies. The ADG841/ADG842 exhibit break-before-make switching action.

The ADG841/ADG842 are available in a 6-lead SC70 package.

FUNCTIONAL BLOCK DIAGRAM

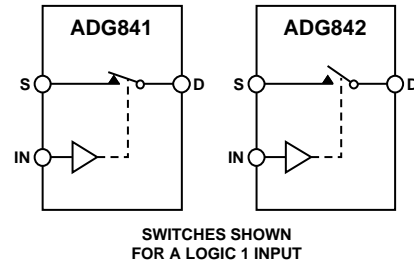


Figure 1.

PRODUCT HIGHLIGHTS

1. <0.48 Ω over full temperature range of -40°C to +125°C.
2. Compatible with 1.8 V CMOS logic.
3. High current handling capability (300 mA continuous current at 3.3 V).
4. Low THD + N (0.02% typ).
5. Tiny SC70 package.

Table 1. ADG841/ADG842 Truth Table

Logic (IN)	ADG841	ADG842
0	Off	On
1	On	Off

Rev. 0

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REVISION HISTORY

4/05—Revision 0: Initial Version

SPECIFICATIONS—2.7 V TO 3.6 V¹

$V_{DD} = 2.7\text{ V to }3.6\text{ V}$, $GND = 0\text{ V}$, unless otherwise noted.

Table 2.

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 V to V_{DD}	V	$V_{DD} = 2.7\text{ V}$
On Resistance (R_{ON})	0.28			Ω typ	$V_{DD} = 2.7\text{ V}$, $V_S = 0\text{ V to }V_{DD}$, $I_{DS} = -100\text{ mA}$
	0.37	0.43	0.48	Ω max	Figure 18
On Resistance Flatness ($R_{FLAT(ON)}$)	0.025			Ω typ	$V_{DD} = 2.7\text{ V}$, $V_S = 0\text{ V to }V_{DD}$, $I_{DS} = -100\text{ mA}$
	0.034	0.044	0.052	Ω max	
LEAKAGE CURRENTS					
Source Off Leakage I_S (OFF)	± 0.2			nA typ	$V_{DD} = 3.6\text{ V}$ $V_S = 0.6\text{ V}/3.3\text{ V}$, $V_D = 3.3\text{ V}/0.6\text{ V}$; Figure 19
Channel On Leakage I_D , I_S (ON)	± 0.2			nA typ	$V_S = V_D = 0.6\text{ V or }3.3\text{ V}$; Figure 20
DIGITAL INPUTS					
Input High Voltage, V_{INH}			2	V min	
Input Low Voltage, V_{INL}			0.8	V max	
Input Current, I_{INL} or I_{INH}	0.005		± 0.1	μA typ μA max	$V_{IN} = V_{INL}$ or V_{INH}
Digital Input Capacitance, C_{IN}	3.2			pF typ	
DYNAMIC CHARACTERISTICS²					
t_{ON}	10.5			ns typ	$R_L = 50\ \Omega$, $C_L = 35\text{ pF}$
	14	15.5	16.5	ns max	$V_S = 1.5\text{ V}$; Figure 21
t_{OFF}	6.5			ns typ	$R_L = 50\ \Omega$, $C_L = 35\text{ pF}$
	7.8	8	8.2	ns max	$V_S = 1.5\text{ V}$; Figure 21
Charge Injection	200			pC typ	$V_S = 1.5\text{ V}$, $R_S = 0\ \Omega$, $C_L = 1\text{ nF}$; Figure 22
Off Isolation	−54			dB typ	$R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 100\text{ kHz}$; Figure 23
Total Harmonic Distortion (THD + N)	0.012			%	$R_L = 32\ \Omega$, $f = 20\text{ Hz to }20\text{ kHz}$, $V_S = 3\text{ V p-p}$
Insertion Loss	−0.02			dB typ	$R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; Figure 24
−3 dB Bandwidth	21			MHz typ	$R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; Figure 24
C_S (OFF)	160			pF typ	
C_D (OFF)	160			pF typ	
C_D , C_S (ON)	238			pF typ	
POWER REQUIREMENTS					
I_{DD}	0.003			μA typ	$V_{DD} = 3.6\text{ V}$ Digital inputs = 0 V or 3.6 V
		1	4	μA max	

¹ Temperature range is -40°C to $+125^\circ\text{C}$

² Guaranteed by design; not subject to production test.

ADG841/ADG842

SPECIFICATIONS—2.5 V ± 0.2 V¹

V_{DD} = 2.5 V ± 0.2 V, GND = 0 V, unless otherwise noted.

Table 3.

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 V to V _{DD}	V	
On Resistance (R _{ON})	0.3			Ω typ	V _{DD} = 2.3 V, V _S = 0 V to V _{DD} , I _{DS} = −100 mA
	0.35	0.4	0.45	Ω max	Figure 18
On Resistance Flatness (R _{FLAT(ON)})	0.025			Ω typ	V _{DD} = 2.3 V, V _S = 0 V to V _{DD} , I _{DS} = −100 mA
	0.04	0.05	0.05	Ω max	
LEAKAGE CURRENTS					
Source Off Leakage I _S (OFF)	±0.2			nA typ	V _{DD} = 2.7 V
Channel On Leakage I _D , I _S (ON)	±0.2			nA typ	V _S = 0.6 V/2.4 V, V _D = 2.4 V/0.6 V; Figure 19
					V _S = V _D = 0.6 V or 2.4 V; Figure 20
DIGITAL INPUTS					
Input High Voltage, V _{INH}			1.7	V min	
Input Low Voltage, V _{INL}			0.7	V max	
Input Current, I _{INL} or I _{INH}	0.005			μA typ	V _{IN} = V _{INL} or V _{INH}
			±0.1	μA max	
Digital Input Capacitance, C _{IN}	3.2			pF typ	
DYNAMIC CHARACTERISTICS²					
t _{ON}	13			ns typ	R _L = 50 Ω, C _L = 35 pF
	16.5	18	19	ns max	V _S = 1.5 V; Figure 21
t _{OFF}	7			ns typ	R _L = 50 Ω, C _L = 35 pF
	8.2	8.4	8.6	ns max	V _S = 1.5 V; Figure 21
Charge Injection	150			pC typ	V _S = 1.25 V, R _S = 0 Ω, C _L = 1 nF; Figure 22
Off Isolation	−54			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 100 kHz; Figure 23
Total Harmonic Distortion (THD + N)	0.022			%	R _L = 32 Ω, f = 20 Hz to 20 kHz, V _S = 1.5 V p-p
Insertion Loss	−0.02			dB typ	R _L = 50 Ω, C _L = 5 pF; Figure 24
−3 dB Bandwidth	21			MHz typ	R _L = 50 Ω, C _L = 5 pF; Figure 24
C _S (OFF)	170			pF typ	
C _D (OFF)	170			pF typ	
C _D , C _S (ON)	238			pF typ	
POWER REQUIREMENTS					
I _{DD}	0.003			μA typ	V _{DD} = 2.7 V
		1	4	μA max	Digital inputs = 0 V or 2.7 V

¹ Temperature range is −40°C to +125°C.

² Guaranteed by design; not subject to production test.

SPECIFICATIONS—1.65 V TO 1.95¹

V_{DD} = 1.65 V to 1.95 V, GND = 0 V, unless otherwise noted.

Table 4.

Parameter	+25°C	–40°C to +85°C	–40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 V to V_{DD}	V	
On Resistance (R_{ON})	0.37			Ω typ	$V_{DD} = 1.8$ V, $V_S = 0$ V to V_{DD} , $I_{DS} = -100$ mA
	0.4	0.84	0.84	Ω max	Figure 18
	0.6	1.8	1.8	Ω max	$V_{DD} = 1.65$ V, $V_S = 0$ V to V_{DD} , $I_{DS} = -100$ mA
On Resistance Flatness ($R_{FLAT(ON)}$)	0.17			Ω typ	$V_{DD} = 1.65$ V, $V_S = 0$ V to V_{DD} , $I_{DS} = -100$ mA
LEAKAGE CURRENTS					
Source Off Leakage I_S (OFF)	± 0.2			nA typ	$V_{DD} = 1.95$ V
Channel On Leakage I_D , I_S (ON)	± 0.2			nA typ	$V_S = 0.6$ V/1.65 V, $V_D = 1.65$ V/0.6 V; Figure 19
					$V_S = V_D = 0.6$ V or 1.65 V; Figure 20
DIGITAL INPUTS					
Input High Voltage, V_{INH}			$0.65 V_{DD}$	V min	
Input Low Voltage, V_{INL}			$0.35 V_{DD}$	V max	
Input Current, I_{INL} or I_{INH}	0.005			μ A typ	$V_{IN} = V_{INL}$ or V_{INH}
			± 0.1	μ A max	
Digital Input Capacitance, C_{IN}	4			pF typ	
DYNAMIC CHARACTERISTICS²					
t_{ON}	19			ns typ	$R_L = 50 \Omega$, $C_L = 35$ pF
	26	28	30	ns max	$V_S = 1.5$ V; Figure 21
t_{OFF}	8			ns typ	$R_L = 50 \Omega$, $C_L = 35$ pF
	9.5	9.8	10	ns max	$V_S = 1.5$ V; Figure 21
Charge Injection	100			pC typ	$V_S = 1$ V, $R_S = 0$ V, $C_L = 1$ nF; Figure 22
Off Isolation	–54			dB typ	$R_L = 50 \Omega$, $C_L = 5$ pF, $f = 100$ kHz; Figure 23
Total Harmonic Distortion (THD + N)	0.14			%	$R_L = 32 \Omega$, $f = 20$ Hz to 20 kHz, $V_S = 1.2$ V p-p
Insertion Loss	–0.02			dB typ	$R_L = 50 \Omega$, $C_L = 5$ pF; Figure 24
–3 dB Bandwidth	21			MHz typ	$R_L = 50 \Omega$, $C_L = 5$ pF; Figure 24
C_S (OFF)	178			pF typ	
C_D (OFF)	178			pF typ	
C_D , C_S (ON)	238			pF typ	
POWER REQUIREMENTS					
I_{DD}	0.003			μ A typ	$V_{DD} = 1.95$ V
		1	4	μ A max	Digital inputs = 0 V or 1.95 V

¹ Temperature range –40°C to +125°C.

² Guaranteed by design; not subject to production test.

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise noted.

Table 5.

Parameter	Rating
V _{DD} to GND	−0.3 V to +4.6 V
Analog Inputs ¹	−0.3 V to V _{DD} + 0.3 V
Digital Inputs ¹	−0.3 V to 4.6 V or 10 mA, whichever occurs first
Peak Current, S or D	
3.3 V Operation	500 mA
2.5 V Operation	460 mA
1.8 V Operation	420 mA (pulsed at 1 ms, 10% duty cycle max)
Continuous Current, S or D	
3.3 V Operation	300 mA
2.5 V Operation	275 mA
1.8 V Operation	250 mA
Operating Temperature Range	
Automotive (Y Version)	−40°C to +125°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
SC70 Package	
θ _{JA} Thermal Impedance	494.8°C/W
Reflow Soldering (Pb-free)	
Peak Temperature	260(+0/−5)°C
Time at Peak Temperature	10 sec to 40 sec

¹ Overvoltages at S or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

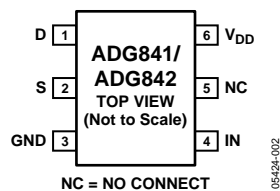


Figure 2. 6-Lead SC70

Table 6. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	D	Drain Terminal. Can be an input or output.
2	S	Source Terminal. Can be an input or output.
3	GND	Ground (0 V) Reference.
4	IN	Logic Control Input.
5	NC	No Connect.
6	V _{DD}	Most Positive Power Supply Potential.

TYPICAL PERFORMANCE CHARACTERISTICS

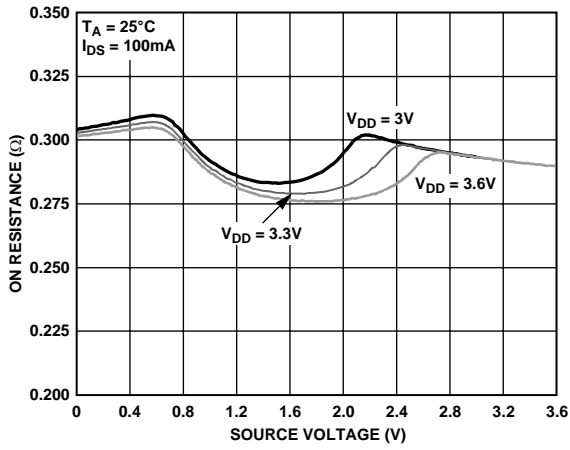


Figure 3. On Resistance vs. V_D (Vs) $V_{DD} = 3.3\text{ V} \pm 0.3\text{ V}$

05424-003

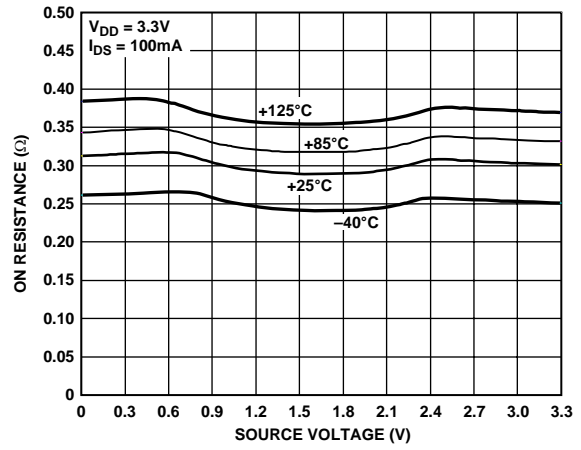


Figure 6. On Resistance vs. V_D (Vs) for Different Temperatures, $V_{DD} = 3.3\text{ V}$

05424-006

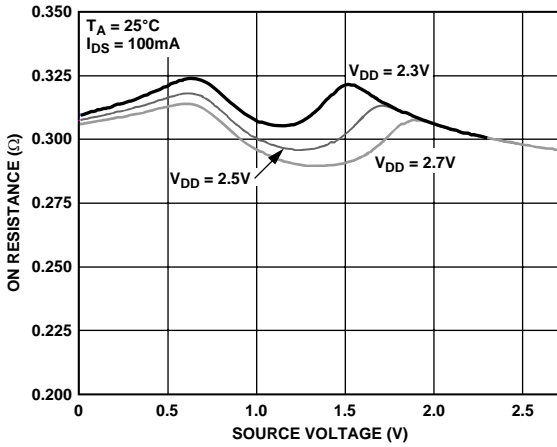


Figure 4. On Resistance vs. V_D (Vs) $V_{DD} = 2.5\text{ V} \pm 0.2\text{ V}$

05424-004

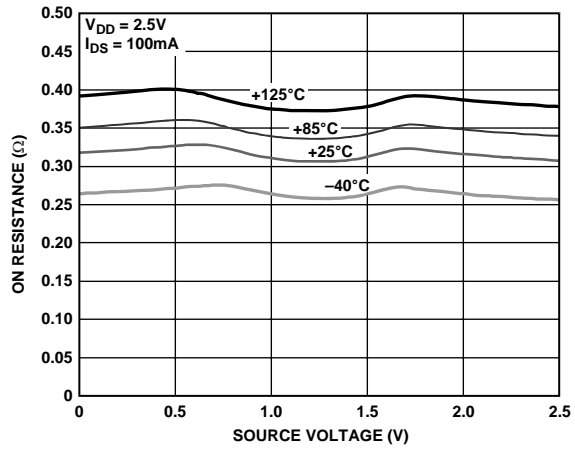


Figure 7. On Resistance vs. V_D (Vs) for Different Temperatures, $V_{DD} = 2.5\text{ V}$

05424-007

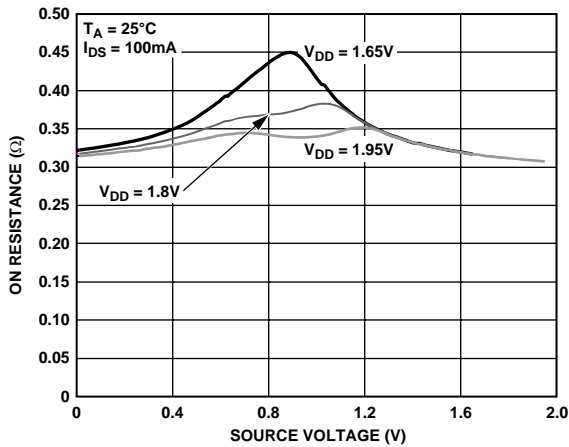


Figure 5. On Resistance vs. V_D (Vs) $V_{DD} = 1.8\text{ V} \pm 0.15\text{ V}$

05424-005

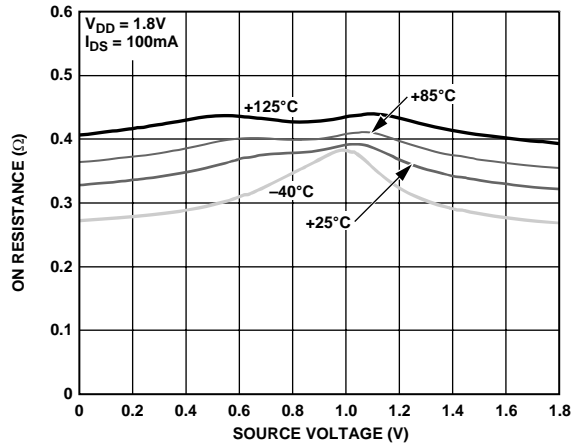


Figure 8. On Resistance vs. V_D (Vs) for Different Temperatures, $V_{DD} = 1.8\text{ V}$

05424-008

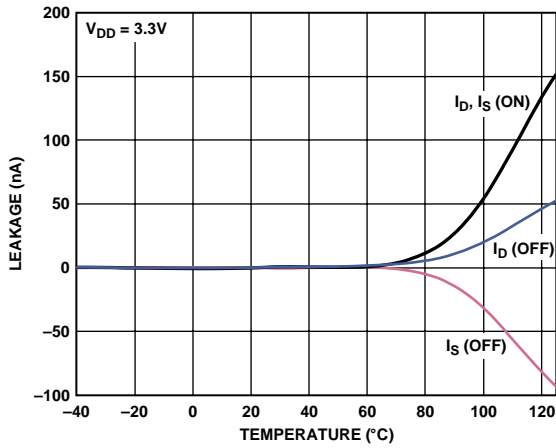


Figure 9. Leakage Current vs. Temperature, $V_{DD} = 3.3V$

05424-009

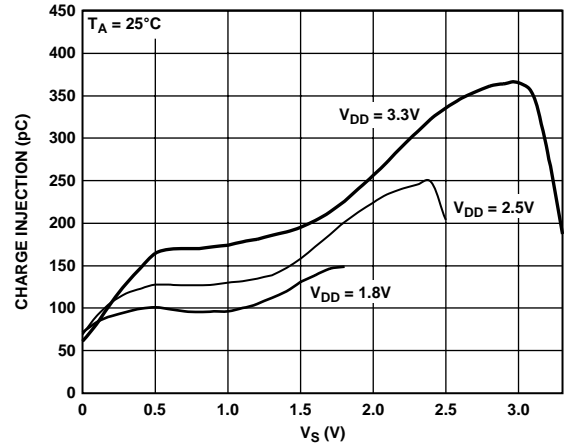


Figure 12. Charge Injection vs. Source Voltage

05424-012

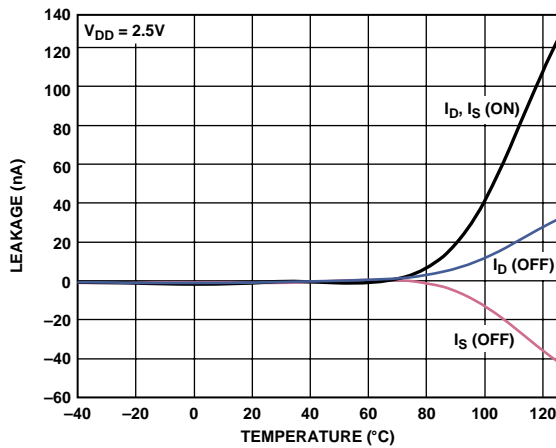


Figure 10. Leakage Current vs. Temperature, $V_{DD} = 2.5V$

05424-010

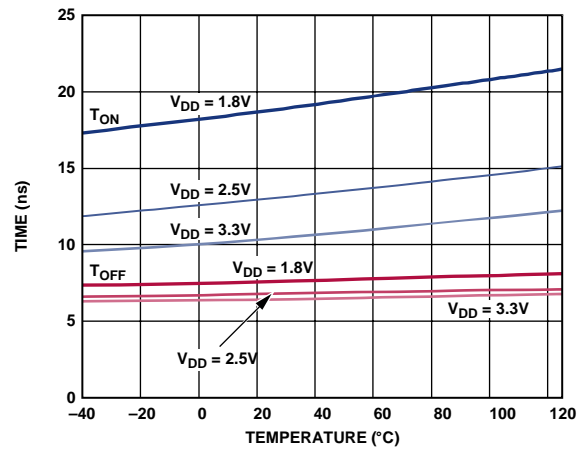


Figure 13. t_{ON}/t_{OFF} Times vs. Temperature

05424-013

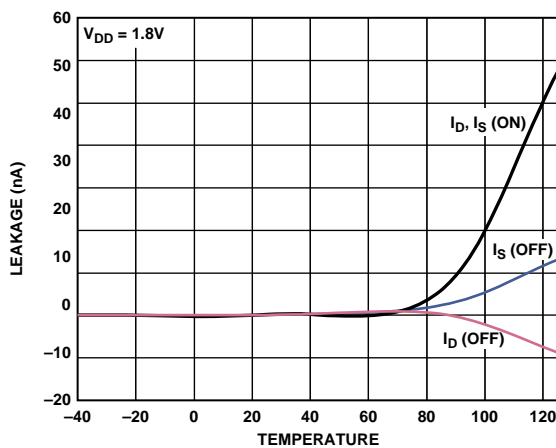


Figure 11. Leakage Current vs. Temperature, $V_{DD} = 1.8V$

05424-011

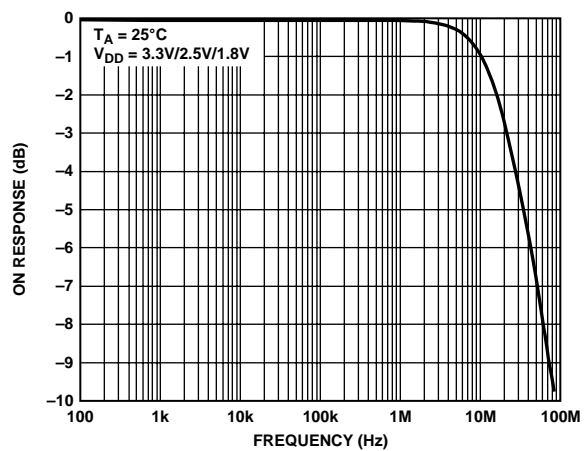


Figure 14. Bandwidth

05424-014

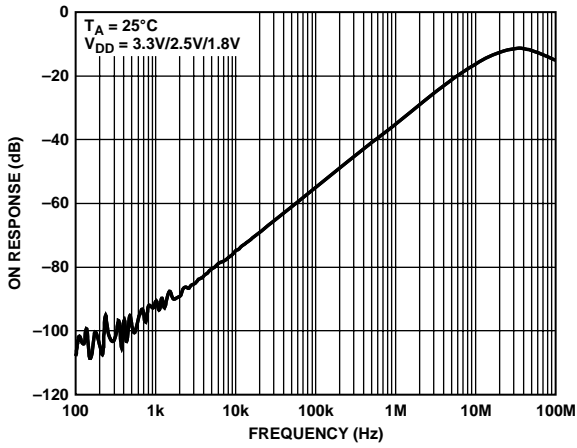


Figure 15. Off Isolation vs. Frequency

05-024-015

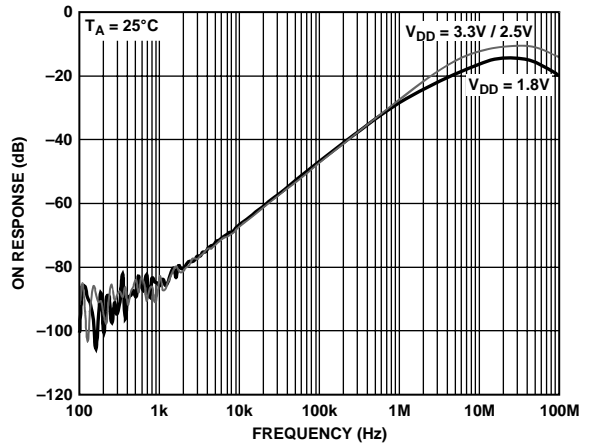


Figure 17. AC PSRR

05-024-017

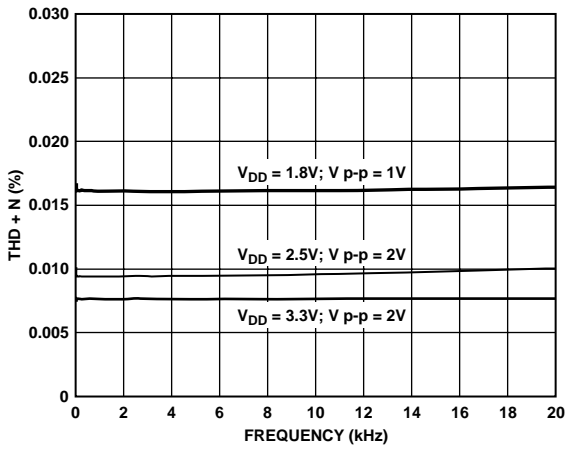


Figure 16. Total Harmonic Distortion + Noise

05-024-016

TERMINOLOGY

I_{DD}

Positive supply current.

V_D (V_S)

Analog voltage on Terminals D and S.

R_{ON}

Ohmic resistance between D and S.

R_{FLAT} (ON)

Flatness is the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

I_S (OFF)

Source leakage current with the switch off.

I_D (OFF)

Drain leakage current with the switch off.

I_D, I_S (ON)

Channel leakage current with the switch on.

V_{INL}

Maximum input voltage for Logic 0.

V_{INH}

Minimum input voltage for Logic 1.

I_{INL} (I_{INH})

Input current of the digital input.

C_S (OFF)

Off switch source capacitance. Measured with reference to ground.

C_D (OFF)

Off switch drain capacitance. Measured with reference to ground.

C_D, C_S (ON)

On switch capacitance. Measured with reference to ground.

C_{IN}

Digital input capacitance.

t_{ON}

Delay time between the 50% and the 90% points of the digital input and switch on condition.

t_{OFF}

Delay time between the 50% and the 90% points of the digital input and switch off condition.

Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during on-off switching.

Off Isolation

A measure of unwanted signal coupling through an off switch.

-3 dB Bandwidth

The frequency at which the output is attenuated by 3 dB.

On Response

The frequency response of the on switch.

Insertion Loss

The loss due to the on resistance of the switch.

THD + N

The ratio of the harmonics amplitude plus noise of a signal to the fundamental.

PSRR

Power Supply Rejection Ratio. This is a measure of the coupling of unwanted ac signals on the power supply to the switch output when the supply is not decoupled.

TEST CIRCUITS

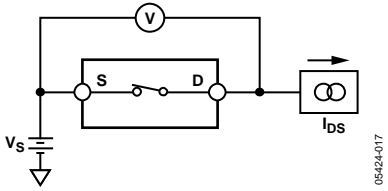


Figure 18. On Resistance

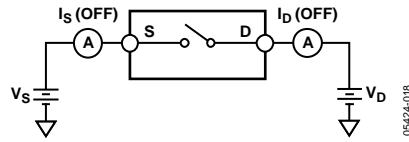


Figure 19. Off Leakage

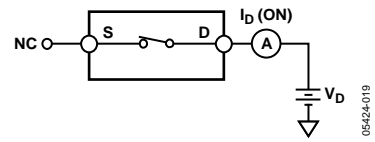


Figure 20. On Leakage

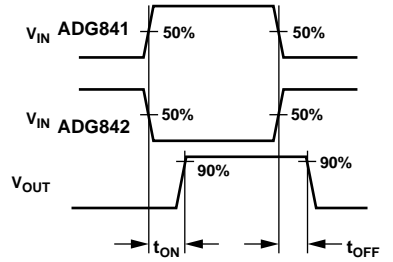
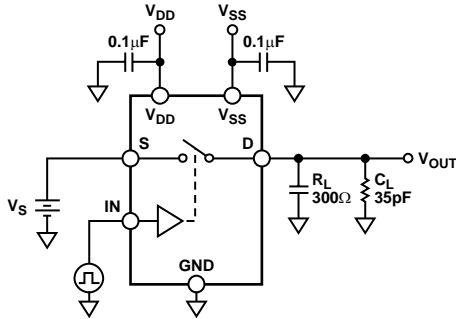


Figure 21. Switching Times, t_{ON} , t_{OFF}

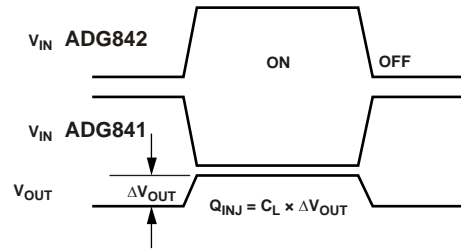
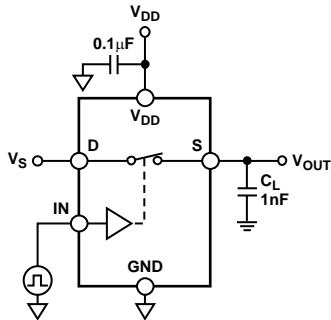


Figure 22. Charge Injection

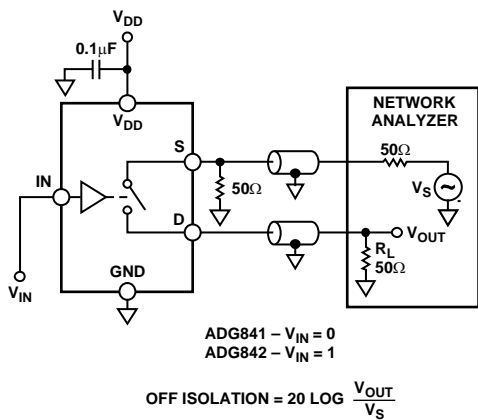


Figure 23. Off Isolation

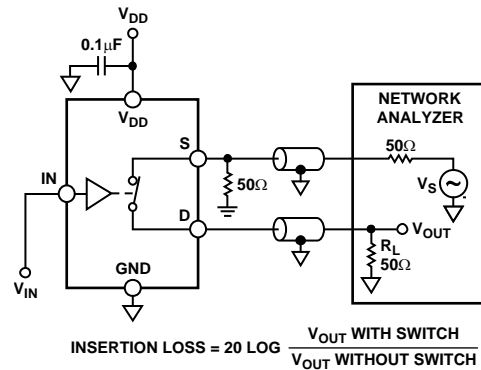
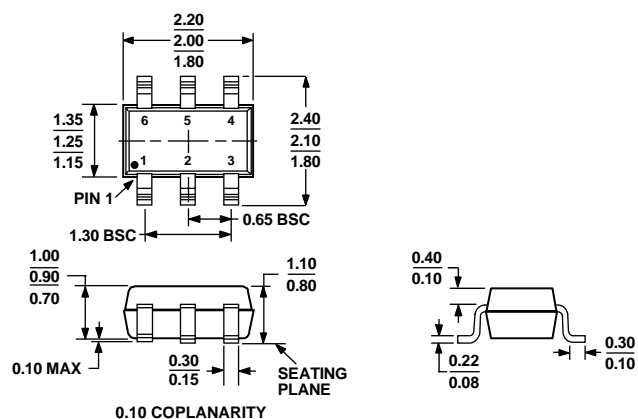


Figure 24. Bandwidth

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-203-AB

Figure 25. 6-Lead Thin Shrink Small Outline Transistor [SC70]
(KS-6)

Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding ¹
ADG841YKSZ-500RL7 ²	-40°C to +125°C	6-Lead Thin Shrink Small Outline Transistor (SC70)	KS-6	SVA
ADG841YKSZ-REEL ²	-40°C to +125°C	6-Lead Thin Shrink Small Outline Transistor (SC70)	KS-6	SVA
ADG841YKSZ-REEL7 ²	-40°C to +125°C	6-Lead Thin Shrink Small Outline Transistor (SC70)	KS-6	SVA
ADG842YKSZ-500RL7 ²	-40°C to +125°C	6-Lead Thin Shrink Small Outline Transistor (SC70)	KS-6	SWA
ADG842YKSZ-REEL ²	-40°C to +125°C	6-Lead Thin Shrink Small Outline Transistor (SC70)	KS-6	SWA
ADG842YKSZ-REEL ²	-40°C to +125°C	6-Lead Thin Shrink Small Outline Transistor (SC70)	KS-6	SWA

¹ Branding on this package is limited to three characters due to space constraints.

² Z = Pb-free part.

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